

## Wideband Driver Amplifier

#### **Key Features and Performance**

- Two Stage Driver Amplifier
- 0.25um pHEMT Technology
- 8-18 GHz Frequency Range
- 13 dBm Nominal Pout
- 17 dB Nominal Gain
- Balanced In/Out for Low VSWR
- 4.5V @ 50mA Self Bias



Typical Measured Small Signal Gain & RL



Typical Measured Pout and NF

Note: Devices designated as EPU are typically early in their characterization process prior to finalizing all electrical and process specifications.

# TGA8399C-EPU

#### **Primary Applications**

- X and Ku band Driver
- Point-to-Point Radio

#### **Release Status**

Engineering Prototype Unit (EPU)



Chip Dimensions 3.5mm x2.4mm x 0.152mm

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### TGA8399C Performance vs Temperature

#### **Advance Product Information**





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### **Recommended Assembly Layout**



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